

## Novel silicon etching technique crafts 3-D gradient refractive index micro-optics

November 28 2016, by Rick Kubetz



This figure shows how the PSi square GRIN microlens focuses and splits TM and TE polarized light, respectively. TM polarized light is focused to one point and TE polarized light is focused to two different points. The refractive index gradient for the square microlens under the two different polarizations is illustrated using the color map overlaid on the lens (blue is low refractive index, and orange is high refractive index). Credit: University of Illinois

A multi-institutional research collaboration has created a novel approach for fabricating three-dimensional micro-optics through the shapedefined formation of porous silicon (PSi), with broad impacts in integrated optoelectronics, imaging, and photovoltaics.

Working with colleagues at Stanford and The Dow Chemical Company,



researchers at the University of Illinois at Urbana-Champaign fabricated 3-D birefringent gradient refractive index (GRIN) micro-optics by electrochemically etching preformed Si micro-structures, like square columns, PSi structures with defined refractive index profiles.

"The emergence and growth of transformation optics over the past decade has revitalized interest in using GRIN optics to control light propagation," explained Paul Braun, the Ivan Racheff Professor of Materials Science and Engineering at Illinois. "In this work, we have figured out how to couple the starting shape of the <u>silicon</u> microstructure and the etch conditions to realize a unique set of desirable optical qualities. For example, these elements exhibit novel polarizationdependent optical functions, including splitting and focusing, expanding the use of <u>porous silicon</u> for a wide range of integrated photonics applications.

"The key is that the optical properties are a function of the etch current," Braun said. "If you change the etch current, you change the refractive index. We also think that the fact that we can create the structures in silicon is important, as silicon is important for photovoltaic, imaging, and integrated optics applications.

"Our demonstration using a three-dimensional, lithographically-defined silicon platform not only displayed the power of GRIN optics, but it also illustrated it in a promising form factor and material for integration within photonic integrated circuits," stated Neil Krueger, a former PhD student in Braun's research group and first author of the paper, "Porous Silicon Gradient Refractive Index Micro-Optics," appearing in *Nano Letters*.

"The real novelty of our work is that we are doing this in a threedimensional optical element," added Krueger, who has recently joined Honeywell Aerospace as a Scientist in Advanced Technology. "This



gives added control over the behavior of our structures given that light follows curvilinear optical paths in optically inhomogeneous media such as GRIN elements. The birefringent nature of these structures is an added bonus because coupled birefringent/GRIN effects provide an opportunity for a GRIN element to perform distinct, polarizationselective operations."

According to the researchers, PSi was initially studied due to its visible luminescence at room temperature, but more recently, as this and other reports have shown, has proven to be a versatile optical material, as its nanoscale porosity (and thus refractive index) can be modulated during its electrochemical fabrication.

"The beauty of this 3D fabrication process is that it is fast and scalable," commented Weijun Zhou at Dow. "Large scale, nanostructured GRIN components can be readily made to enable a variety of new industry applications such as advanced imaging, microscopy, and beam shaping."

"Because the etching process enables modulation of the <u>refractive index</u>, this approach makes it possible to decouple the optical performance and the physical shape of the optical element," Braun added. "Thus, for example, a lens can be formed without having to conform to the shape that we think of for a lens, opening up new opportunities in the design of integrated silicon optics."

**More information:** Neil A. Krueger et al, Porous Silicon Gradient Refractive Index Micro-Optics, *Nano Letters* (2016). <u>DOI:</u> <u>10.1021/acs.nanolett.6b02939</u>

Provided by University of Illinois at Urbana-Champaign



Citation: Novel silicon etching technique crafts 3-D gradient refractive index micro-optics (2016, November 28) retrieved 4 May 2024 from <u>https://phys.org/news/2016-11-silicon-etching-technique-crafts-d.html</u>

This document is subject to copyright. Apart from any fair dealing for the purpose of private study or research, no part may be reproduced without the written permission. The content is provided for information purposes only.